

Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.28 \text{ V}$ at $I_F = 5.0 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 20 A			
V_{RRM}	45 V			
I _{FSM}	240 A			
V _F at I _F = 20 A	0.41 V			
T _J max.	150 °C			
Package	ITO-220AB			
Diode variation	Dual common cathode			

FEATURES

Trench MOS Schottky technology

· Low forward voltage drop, low power losses

· High efficiency operation

HALOGEN Solder bath temperature 275 °C max. 10 s, per FREE JESD 22-B106

· Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VFT4045C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	40	^	
	per diode		20	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	240	А	
Isolation voltage from termal to heatsink t = 1 min		V _{AC}	1500	V	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.41	-	V	
	I _F = 10 A			0.44	-		
	I _F = 20 A			0.50	0.58		
	I _F = 5 A	T _A = 125 °C		0.28	-		
	I _F = 10 A			0.33	-		
	I _F = 20 A			0.41	0.50		
Reverse current per diode	V - 45 V	T _A = 25 °C	I _R ⁽²⁾	=	3000	μA	
	$V_R = 45 \text{ V}$	T _A = 125 °C	'R (-)	18	50	mA	

Notes

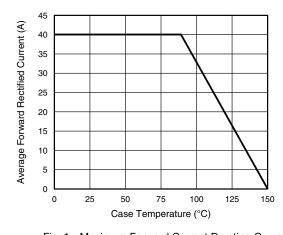
(1) Pulse test: 300 µs pulse width, 1 % duty cycle

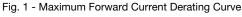
(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT4045C	UNIT
Typical thermal resistance	per diode	$R_{ hetaJC}$	5.0	°C/W
	per device		3.5	J 0/VV

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	VFT4045C-M3/4W	1.76	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





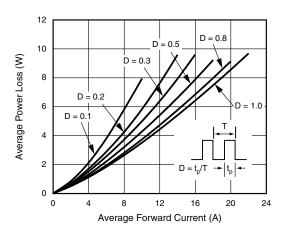


Fig. 2 - Forward Power Loss Characteristics Per Diode



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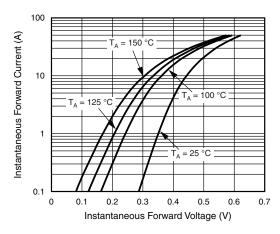


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

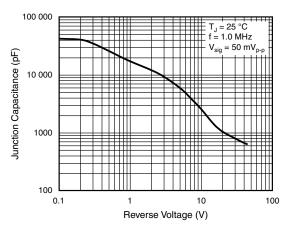


Fig. 5 - Typical Junction Capacitance Per Diode

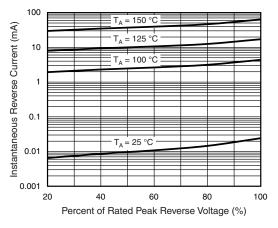


Fig. 4 - Typical Reverse Characteristics Per Diode

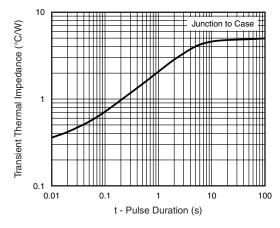
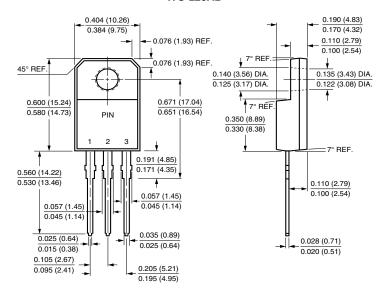


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB





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